Front Matter: Volume 6669
Seventh International Conference on Solid State Lighting

Ian T. Ferguson
Nadarajah Narendran
Tsunemasa Taguchi
Ian E. Ashdown
Editors

27–29 August 2007
San Diego, California, USA

Sponsored and Published by
SPIE

Volume 6669
The papers included in this volume were part of the technical conference cited on the cover and title page. Papers were selected and subject to review by the editors and conference program committee. Some conference presentations may not be available for publication. The papers published in these proceedings reflect the work and thoughts of the authors and are published herein as submitted. The publisher is not responsible for the validity of the information or for any outcomes resulting from reliance thereon.

Please use the following format to cite material from this book:


ISSN 0277-786X
ISBN 9780819468178

Published by
SPIE
P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
SPIE.org

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Printed in the United States of America.

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   Ian T. Ferguson, Georgia Institute of Technology (USA)

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Introduction

The seventh conference on Solid State Lighting, part of the SPIE Annual Meeting, took place from 27–29 August 2007 in San Diego, California.

Contained in these proceedings are the 39 submitted papers of invited and contributing presenters in this conference. The topics covered by these papers range from semiconductor fabrication and characterization to solid state lighting systems development. They are representative of an unmistakable progression from academic research to industrial commercialization, fulfilling a promise that began with the first solid state lighting conference in 2001. At the same time, they also demonstrate that much exciting work remains to be done in the field.

The conference chairs would like to thank SPIE for hosting this meeting, as well as the program committee members, the authors, and the session chairs for making this meeting a technical success, and for providing valued and timely research on solid state lighting.

Ian T. Ferguson
Nadarajah Narendran
Tsunemasa Taguchi
Ian E. Ashdown